## INTEGRATED CIRCUITS

# DATA SHEET UMA1021AM Low-voltage frequency synthesizer for radio telephones

Product specification Supersedes data of 1998 Mar 03 File under Integrated Circuits, IC17







1998 Nov 19

## UMA1021AM

#### FEATURES

- Low phase noise
- Low current from 3 V supply
- Fully programmable main divider
- 3-line serial interface bus
- Independent fully programmable reference divider, driven from external crystal oscillator
- Hard and soft power-down control.

#### APPLICATIONS

- 900 MHz and 2 GHz mobile telephones
- · Portable battery-powered radio equipment.

#### **GENERAL DESCRIPTION**

The UMA1021AM BICMOS device integrates a prescaler, programmable dividers, and a phase comparator to implement a phase-locked loop.

The device is designed to operate from 3 NiCd cells, in pocket phones, with low current and nominal 3 V supplies.

The synthesizer operates at RF input frequencies up to 2.2 GHz with a fully programmable reference divider. All divider ratios are supplied via a 3-wire serial programming bus.

Separate power and ground pins are provided to the analog (charge pump) and digital circuits. The ground leads should be externally short-circuited to prevent large currents flowing across the die and thus causing damage.  $V_{DD1}$  and  $V_{DD2}$  must also be at the same potential ( $V_{DD}$ ).  $V_{CC}$  must be equal to or greater than  $V_{DD}$  for wider control range of the Voltage Controlled Oscillator (VCO), e.g.  $V_{DD} = 3$  V and  $V_{CC} = 5$  V.

The charge pump current (phase detector gain) is fixed by an external resistor at pin  $I_{SET}$  and controlled via the serial interface. Only a passive loop filter is necessary; the charge pump functions within a wide voltage compliance range to improve the overall system performance.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>DD1</sub> , V <sub>DD2</sub>	digital supply voltage	$V_{DD1} = V_{DD2} = V_{DD}$	2.7	-	5.5	V
V <sub>CC</sub>	analog supply voltage for charge pump	$V_{CC} \ge V_{DD}$	2.7	-	5.5	V
I <sub>tot</sub>	total supply current (I <sub>DD</sub> + I <sub>CC</sub> )	$V_{CC} = V_{DD} = 5.5 V$	-	10	_	mA
I <sub>tot(pd)</sub>	total supply current in Power-down mode ( $I_{DD} + I_{CC}$ )	logic levels 0 V or $V_{DD}$	-	5	-	μA
f <sub>RF</sub>	RF input frequency		300	_	2200	MHz
f <sub>xtal</sub>	crystal reference oscillator input frequency		3	-	35	MHz
f <sub>ph(comp)</sub>	phase comparator frequency		-	200	-	kHz
T <sub>amb</sub>	operating ambient temperature		-30	-	+85	°C

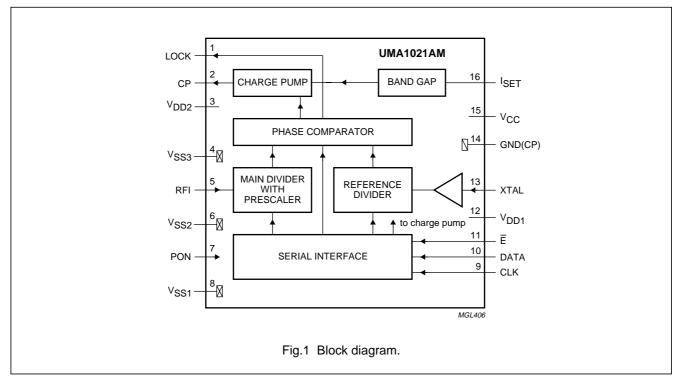
#### QUICK REFERENCE DATA

#### **ORDERING INFORMATION**

		PACKAGE	
	NAME	DESCRIPTION	VERSION
UMA1021AM	SSOP16	plastic shrink small outline package; 16 leads; body width 4.4 mm	SOT369-1

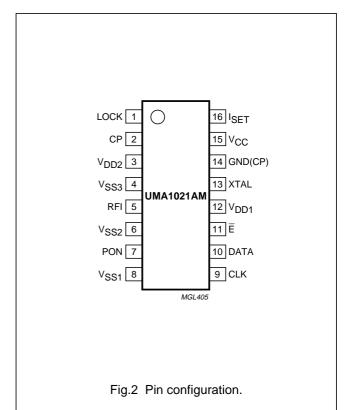
## UMA1021AM

#### **BLOCK DIAGRAM**



#### PINNING

SYMBOL	PIN	DESCRIPTION
LOCK	1	out-of-lock detector output
СР	2	charge pump output
V <sub>DD2</sub>	3	digital supply voltage
V <sub>SS3</sub>	4	ground 3 (0 V)
RFI	5	2 GHz main divider input
V <sub>SS2</sub>	6	ground 2 (0 V)
PON	7	power-on input
V <sub>SS1</sub>	8	ground 1 (0 V)
CLK	9	programming bus clock input
DATA	10	programming bus data input
Ē	11	programming bus enable input (active LOW)
V <sub>DD1</sub>	12	digital supply voltage
XTAL	13	crystal frequency input
GND(CP)	14	ground for charge pump
V <sub>CC</sub>	15	analog supply voltage for charge pump
I <sub>SET</sub>	16	charge pump current setting with external resistor from this pin to ground



#### FUNCTIONAL DESCRIPTION

#### Main divider

The main divider is clocked at pin RFI by the RF signal which is AC-coupled from an external VCO. The divider operates with signal levels from 50 to 225 mV (RMS) and at frequencies from 300 MHz to 2.2 GHz. It consists of a fully programmable bipolar prescaler followed by a CMOS counter. The main divider allows programmable ratios from 512 to 131071 inclusive.

#### **Reference divider**

The reference divider is clocked by the signal at pin XTAL. The applied input signal should be AC-coupled. The circuit operates with levels from 50 up to 500 mV (RMS) and at frequencies from 3 to 35 MHz. Any divide ratios from 8 to 2047 inclusive can be programmed.

#### Phase comparator and charge pump

The phase detector is driven by the edges of the output signals of the main and reference dividers. The detector produces current pulses at pin CP. The pulse duration is equal to the difference in time of arrival of the edges from the two dividers. If the main divider edge arrives first, pin CP sinks current. If the reference divider edge arrives first, pin CP sources current.

The current at pin CP can be controlled via the serial programming bus as a multiple of the reference current set by an external pull-down resistor connected between pin I<sub>SET</sub> and ground (see Table 2). Pin CP remains active except in the Power-down mode.

Additional circuitry is included to ensure that the gain of the phase detector remains linear even for small phase errors.

#### **Out-of-lock detector**

The out-of-lock detector is enabled or disabled via the serial interface by setting bit OOL (dt12) HIGH or LOW (see Table 1). An open-drain transistor drives the output pin LOCK. It is recommended to keep the sink current in the LOW state below 400  $\mu$ A by applying a pull-up resistor from pin LOCK to the positive supply. When the out-of-lock detector is enabled pin LOCK is HIGH if the error at the phase detector input is less than approximately 25 ns, otherwise pin LOCK is LOW. If the out-of-lock detector is disabled, pin LOCK remains HIGH.

#### Serial programming bus

A simple 3-line unidirectional serial bus is used to program the circuit.

The 3 lines are DATA (data bits), CLK (clock pulses) and  $\overline{E}$  (enable signal). The data sent to the device is loaded in bursts framed by  $\overline{E}$ . Programming clock edges and their appropriate data bits are ignored until  $\overline{E}$  goes active LOW. The programmed information is loaded into the addressed latch when  $\overline{E}$  returns HIGH. During normal operation,  $\overline{E}$  should be kept HIGH. Only the last 21 bits serially clocked into the device are retained within the programming register. Additional leading bits are ignored, and no check is made on the number of clock pulses. The fully static CMOS design uses virtually no current when the programming bus is inactive. It can always capture new programmed data even during power-down.

When the synthesizer is switched on, the presence of a signal at the reference divider input is required for correct programming.

#### Data format

The data format is shown in Table 1. The first bit entered is dt16, the last bit is ad0.

The leading bits (dt16 to dt0) make up the data field.

The four trailing bits (ad3 to ad0) are the address field. The UMA1021AM uses 4 of the 16 available addresses. These are chosen for compatibility with other Philips Semiconductors radio telephone ICs. The trailing address bits are decoded on the rising edge of  $\overline{E}$ . This produces an internal load pulse to store the data in the addressed latch. To avoid erroneous divider ratios, the load pulse is not allowed during data reads by the frequency dividers. This condition is guaranteed by respecting a minimum  $\overline{E}$  pulse width after data transfer.

For the divider ratios, the first bits entered (PM16 and PR10) are the Most Significant Bits (MSBs).

The test register (address 0000) does not normally need to be programmed. However, if it is programmed all bits in the data field should be set to logic 0.

#### Power-down mode

The synthesizer is switched on when both the power-on input (PON) and the programmed bit dt6 (sPON) are HIGH. When switched on, the dividers and phase detector are synchronized to avoid random phase errors. When switched off, the phase detector is synchronized to avoid interrupting of the charge pump pulses.

The UMA1021AM has a very low current consumption in the Power-down mode.

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#### **Philips Semiconductors**

# Low-voltage frequency synthesizer for radio telephones

## UMA1021AM

Product specification

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## UMA1021AM

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{DD1}, V_{DD2}$	digital supply voltage		-0.3	+5.5	V
V <sub>CC</sub>	analog supply voltage for charge pump		-0.3	+5.5	V
$\Delta V_{CC-DD}$	supply voltage difference between the analog and digital supply voltages		-0.3	+5.5	V
V <sub>n</sub>	voltage at pins 5, 7, 9, 10 and 11 at pins 1, 2, 13 and 16		-0.3 -0.3	V <sub>DD</sub> + 0.3 V <sub>CC</sub> + 0.3	V V
$\Delta V_{GND}$	difference in voltage between any of pins GND(CP), $V_{SS1}$ , $V_{SS2}$ and $V_{SS3}$	these pins should be connected together	-0.3	+0.3	V
P <sub>tot</sub>	total power dissipation		-	85	mW
T <sub>stg</sub>	storage temperature		-55	+125	°C
T <sub>amb</sub>	operating ambient temperature		-30	+85	°C
T <sub>j(max)</sub>	maximum junction temperature		-	150	°C

#### HANDLING

All pins withstand the ESD class 2 test in accordance with "EIA/JESD22-A114-A".

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	142	K/W

## **UMA1021AM**

#### CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supplies; pin	s 3, 12 and 15		•	•		•
V <sub>DD1</sub> , V <sub>DD2</sub>	digital supply voltage	$V_{DD1} = V_{DD2} = V_{DD}$	2.7	_	5.5	V
V <sub>CC</sub>	analog supply voltage for charge pump	$V_{CC} \ge V_{DD}$	2.7	-	5.5	V
I <sub>DD</sub>	total digital supply current of synthesizer (I <sub>DD1</sub> + I <sub>DD2</sub> )	V <sub>DD</sub> = 5.5 V	-	7	9.5	mA
I <sub>CC</sub>	analog supply current of charge pump	$V_{CC} = 5.5 \text{ V};$ R <sub>set</sub> = 5.6 kΩ	-	3	3.8	mA
I <sub>tot(pd)</sub>	total supply current in Power-down mode (I <sub>DD</sub> + I <sub>CC</sub> )	logic levels 0 V or $V_{DD}$	-	5	50	μΑ
RF main divid	ler input; pin 5			•		•
f <sub>RF</sub>	RF input frequency		300	_	2200	MHz
V <sub>RF(rms)</sub>	input signal level (RMS value)	AC-coupled; series resistance $R_s = 50 \Omega$	50	-	225	mV
D/D <sub>m</sub>	main divider ratio		512	_	131071	
Zi	input impedance (real part)	f <sub>RF</sub> = 1 GHz	_	750	_	Ω
		f <sub>RF</sub> = 2 GHz	-	130	-	Ω
Ci	input capacitance	f <sub>RF</sub> = 1 GHz	-	0.5	_	pF
		f <sub>RF</sub> = 2 GHz	-	1.5	-	pF
Reference div	vider input; pin 13					
f <sub>xtal</sub>	crystal reference oscillator input frequency		3	-	35	MHz
V <sub>xtal(rms)</sub>	sinusoidal input signal level (RMS value)		50	-	500	mV
D/D <sub>ref</sub>	reference divider ratio		8		2047	
Zi	input impedance (real part)	f <sub>xtal</sub> = 13 MHz	_	10	_	kΩ
Ci	input capacitance	f <sub>xtal</sub> = 13 MHz	-	1.3	-	pF
Phase compa	rator					
f <sub>ph(comp)</sub>	phase comparator frequency		-	200	_	kHz
f <sub>loop(max)</sub>	maximum loop comparison frequency		-	2000	-	kHz
Charge pump	current setting; pin 16					
R <sub>set</sub>	external resistor	connected between pin 16 and ground	5.6	-	12	kΩ
V <sub>set</sub>	regulated voltage	$R_{set} = 5.6 \text{ k}\Omega$	_	1.2	_	V

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Charge pump	output; pin 2				-	
V <sub>o(compl)</sub>	compliance output voltage	R <sub>set</sub> = 5.6 kΩ	0.4	_	$V_{CC} - 0.4$	V
I <sub>o(err)</sub>	output current error	R <sub>set</sub> = 5.6 kΩ	-25	-	+25	%
I <sub>o(match)</sub>	sink-to-source current matching	$R_{set} = 5.6 \ k\Omega$	-	±5	-	%
IL	leakage current	$\label{eq:Rset} \begin{array}{l} R_{set} = 5.6 \ \text{k}\Omega; \\ \text{charge pump off;} \\ V_{o(compl)} = \frac{1}{2}V_{CC} \end{array}$	-5	±1	+5	nA
Phase noise	•	•	•	•		
N <sub>900</sub>	RF synthesizer's contribution to close-in phase noise of 900 MHz VCO signal inside the closed loop bandwidth		_	-88	-	dBc/Hz
N <sub>1800</sub>	RF synthesizer's contribution to close-in phase noise of 1.8 GHz VCO signal inside the closed loop bandwidth	$\label{eq:transform} \begin{array}{l} f_{xtal} = 13 \text{ MHz};\\ V_{xtal} = 0 \text{ dBm};\\ f_{ph(comp)} = 200 \text{ kHz} \end{array}$	-	-82	-	dBc/Hz
Interface logi	c inputs; pins 7, 9, 10 and 11	•	•	•		
V <sub>IH</sub>	HIGH-level input voltage		0.7V <sub>DD</sub>	-	V <sub>DD</sub> + 0.3	V
VIL	LOW-level input voltage		-0.3	_	0.3V <sub>DD</sub>	V
I <sub>i(bias)</sub>	input bias current	logic 1 or logic 0	-5	-	+5	μA
Ci	input capacitance		_	2	-	pF
Out-of-lock d	etector output; pin 1					
V <sub>OL</sub>	LOW-level output voltage	open-drain output	-	-	0.3V <sub>DD</sub>	V
$E_{\phi(th)}$	threshold phase error	open-drain output	_	25	_	ns

## UMA1021AM

#### SERIAL BUS TIMING CHARACTERISTICS

 $V_{DD1} = V_{DD2} = V_{CC} = 3$  V;  $T_{amb} = 25$  °C; unless otherwise specified.

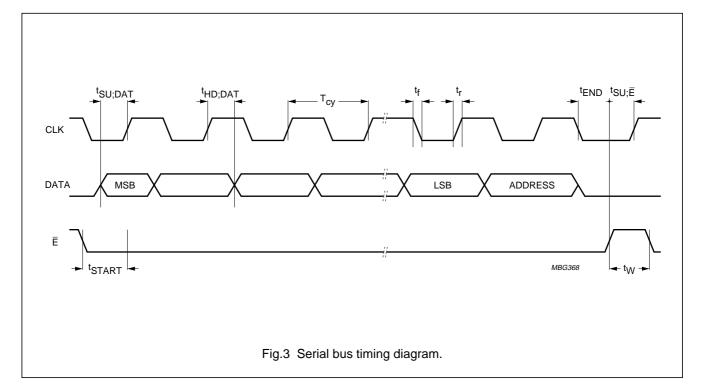
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Serial program	nming clock; CLK					•
t <sub>r</sub>	rise time		-	10	40	ns
t <sub>f</sub>	fall time		-	10	40	ns
T <sub>cy</sub>	clock cycle time		100	-	-	ns
Enable progra	amming; Ē					
t <sub>START</sub>	delay to rising clock edge		40	-	-	ns
t <sub>END</sub>	delay from last falling clock edge		-20	_	-	ns
t <sub>W</sub>	minimum inactive pulse width	note 1	4000	_	-	ns
t <sub>SU;Ē</sub>	enable set-up time to next clock edge		20	_	-	ns
Register seria	Il input data; DATA				·	
t <sub>SU;DAT</sub>	input data to clock set-up time		20	-	-	ns
t <sub>HD;DAT</sub>	input data to clock hold time		20	-	-	ns

#### Note

1. The minimum pulse width  $(t_W)$  can be smaller than 4000 ns when the both conditions are fulfilled:

a) Main divider input frequency: 
$$f_{RF} > \frac{447}{t_W}$$

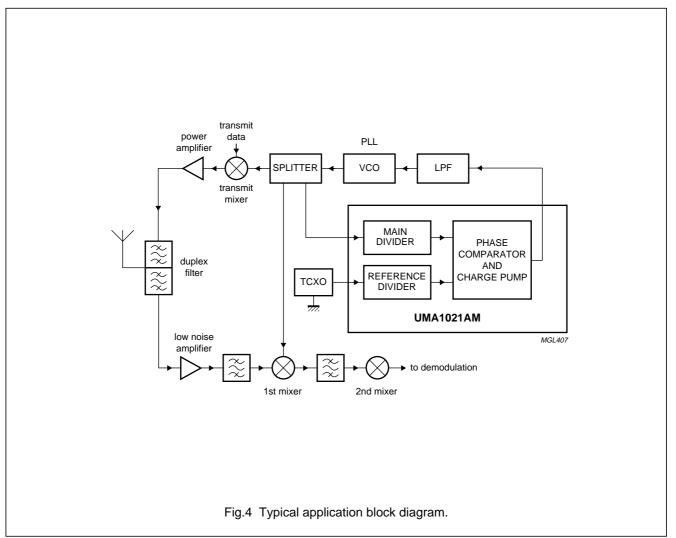
b) Reference divider input frequency: 
$$f_{xtal} > \frac{3}{t_W}$$

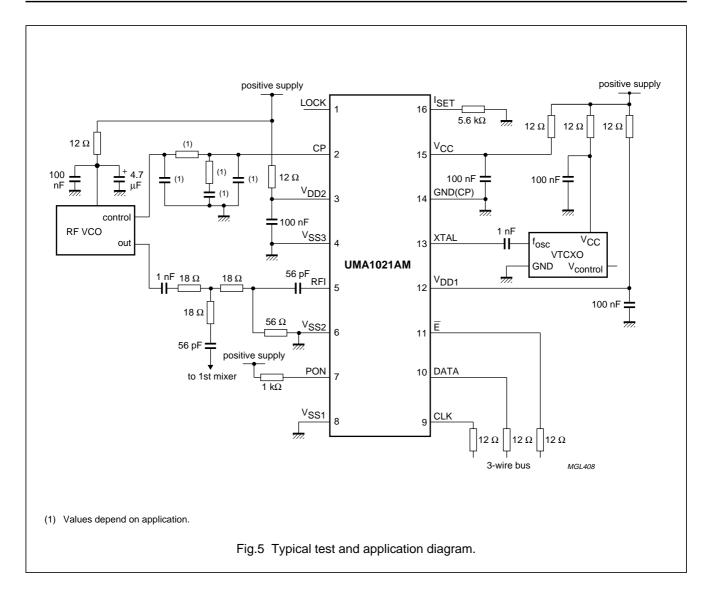


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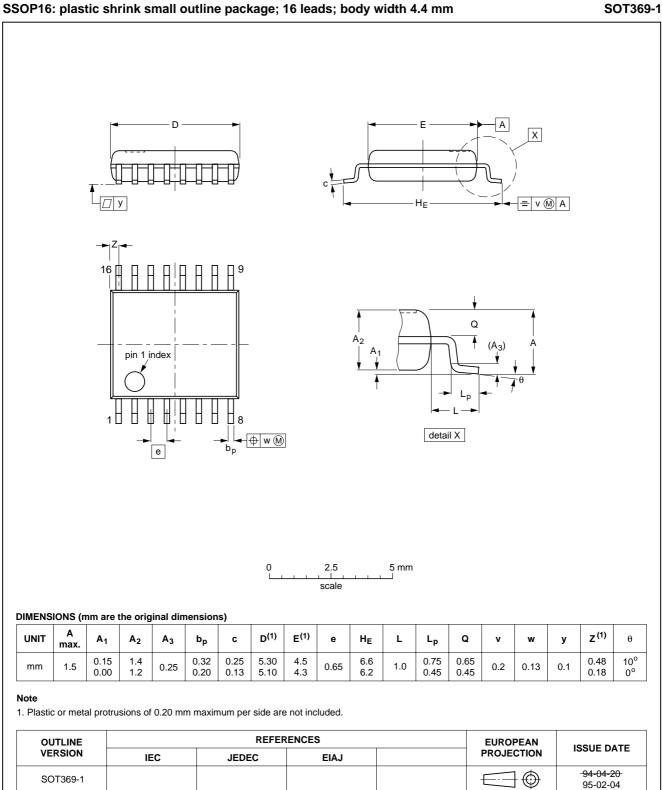
Product specification

#### **APPLICATION INFORMATION**





#### PACKAGE OUTLINE



**UMA1021AM** 

# Low-voltage frequency synthesizer for radio telephones

## SOLDERING

#### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (order code 9398 652 90011).

#### **Reflow soldering**

Reflow soldering techniques are suitable for all SSOP packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

#### Wave soldering

Wave soldering is **not** recommended for SSOP packages. This is because of the likelihood of solder bridging due to closely-spaced leads and the possibility of incomplete solder penetration in multi-lead devices. If wave soldering cannot be avoided, the following conditions must be observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow and must incorporate solder thieves at the downstream end.

#### Even with these conditions, only consider wave soldering SSOP packages that have a body width of 4.4 mm, that is SSOP16 (SOT369-1) or SSOP20 (SOT266-1).

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### **Repairing soldered joints**

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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#### DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.
Application information	
Where englighting information	on is given, it is advisory and does not form part of the encodiation

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

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